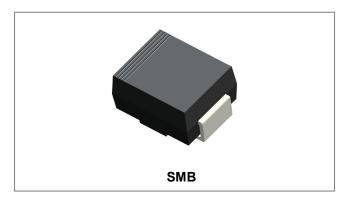


RoHS HF

SK54B SCHOTTKY RECTIFIER



Features

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term
- reliability
- Green products in compliance the ROHS directive
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage	V_{RRM}	-		
Working Peak Reverse Voltage	V_{RWM}		40	V
DC Blocking Voltage	V_R			
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C =105°C, rectangular wave form	5	Α
Peak Repetitive Forward Current	I _{FRM}	At Rated V_R , Square Wave, 20KHZ, T_C =80 $^{\circ}$ C	10	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T _c = 25 °C	125	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 5A, Pulse, T _J = 25 °C	0.58	0.65	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.50	0.63	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.01	1.0	mA
	I _{R2}	$@V_R = \text{rated } V_{R_1} T_J = 125 ^{\circ}\text{C}$	8	30	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	130	280	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

^{*} Pulse width < 300 µs, duty cycle < 2%

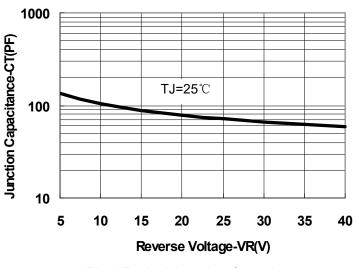




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T_{stg}	-	-55 to +150	°C
Typical Thermal Resistance to Lead	$R_{ heta JL}$	-	17	°C/W
Typical Thermal Resistance to Ambiebt	$R_{\theta JA}$	-	75	°C/W
Approximate Weight	wt	-	0.09	g

Ratings and Characteristics Curves



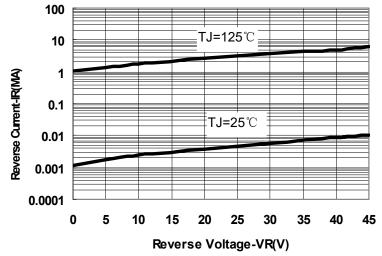


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

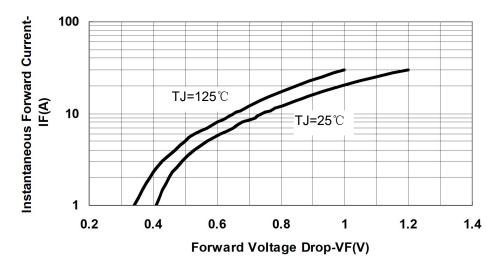


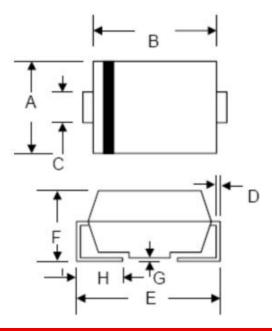
Fig.3-Typical Instantaneous Forward Voltage Characteristics

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Mechanical Dimensions SMB



SYMBOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
Α	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.80	2.20	0.071	0.087	
D	0.152	0.305	0.006	0.012	
Е	4.80	5.59	0.189	0.220	
F	2.10	2.60	0.083	0.102	
G	0.051	0.203	0.002	0.008	
Н	0.76	1.52	0.030	0.060	

Ordering Information

Device	Package	Shipping
SK54B	SMB	3000pcs / reel
SK54BTR	SMB	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

SK54B xxxxxx

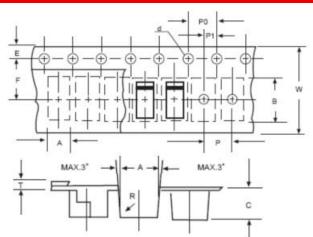
Where XXXXX is YYWWL

SK = Device Type
5 = Forward Current (5A)
4 = Reverse Voltage (40V)
B = Package type
YY = Year
WW = Week

Cautions: Molding resin
Epoxy resin UL:94V-0

= Lot Number

Carrier Tape Specification SMB



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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